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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, I ² S, LCD, POR, PWM, WDT
Number of I/O	51
Program Memory Size	192KB (192K x 8)
Program Memory Type	FLASH
EEPROM Size	6K x 8
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TFBGA
Supplier Device Package	64-TFBGA (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l083rzh6

3.18.3	Basic timer (TIM6, TIM7)	32
3.18.4	SysTick timer	32
3.18.5	Independent watchdog (IWDG)	32
3.18.6	Window watchdog (WWDG)	33
3.19	Communication interfaces	33
3.19.1	I2C bus	33
3.19.2	Universal synchronous/asynchronous receiver transmitter (USART) . .	34
3.19.3	Low-power universal asynchronous receiver transmitter (LPUART) . .	35
3.19.4	Serial peripheral interface (SPI)/Inter-integrated sound (I2S)	35
3.19.5	Universal serial bus (USB)	36
3.20	Clock recovery system (CRS)	36
3.21	Cyclic redundancy check (CRC) calculation unit	36
3.22	Serial wire debug port (SW-DP)	36
4	Pin descriptions	37
5	Memory mapping	56
6	Electrical characteristics	57
6.1	Parameter conditions	57
6.1.1	Minimum and maximum values	57
6.1.2	Typical values	57
6.1.3	Typical curves	57
6.1.4	Loading capacitor	57
6.1.5	Pin input voltage	57
6.1.6	Power supply scheme	58
6.1.7	Optional LCD power supply scheme	59
6.1.8	Current consumption measurement	59
6.2	Absolute maximum ratings	60
6.3	Operating conditions	62
6.3.1	General operating conditions	62
6.3.2	Embedded reset and power control block characteristics	64
6.3.3	Embedded internal reference voltage	65
6.3.4	Supply current characteristics	66
6.3.5	Wakeup time from low-power mode	78
6.3.6	External clock source characteristics	80
6.3.7	Internal clock source characteristics	84

6.3.8	PLL characteristics	87
6.3.9	Memory characteristics	88
6.3.10	EMC characteristics	89
6.3.11	Electrical sensitivity characteristics	91
6.3.12	I/O current injection characteristics	92
6.3.13	I/O port characteristics	93
6.3.14	NRST pin characteristics	97
6.3.15	12-bit ADC characteristics	98
6.3.16	DAC electrical specifications	104
6.3.17	Temperature sensor characteristics	106
6.3.18	Comparators	107
6.3.19	Timer characteristics	108
6.3.20	Communications interfaces	108
6.3.21	LCD controller	117
7	Package information	119
7.1	LQFP100 package information	119
7.2	UFBGA100 package information	122
7.3	LQFP64 package information	125
7.4	TFBGA64 package information	128
7.5	LQFP48 package information	131
7.6	Thermal characteristics	134
7.6.1	Reference document	135
8	Part numbering	136
9	Revision history	137

List of figures

Figure 1.	STM32L083xx block diagram	12
Figure 2.	Clock tree	24
Figure 3.	STM32L083xx LQFP100 pinout - 14 x 14 mm	37
Figure 4.	STM32L083xx UFBGA100 ballout - 7x 7 mm.	38
Figure 5.	STM32L083xx LQFP64 pinout - 10 x 10 mm	39
Figure 6.	STM32L083xx TFBGA64 ballout - 5x 5 mm.	40
Figure 7.	STM32L083xx LQFP48 pinout - 7 x 7 mm	41
Figure 8.	Memory map	56
Figure 9.	Pin loading conditions.	57
Figure 10.	Pin input voltage	57
Figure 11.	Power supply scheme	58
Figure 12.	Optional LCD power supply scheme	59
Figure 13.	Current consumption measurement scheme	59
Figure 14.	IDD vs VDD, at TA= 25/55/85/105 °C, Run mode, code running from Flash memory, Range 2, HSE, 1WS	68
Figure 15.	IDD vs VDD, at TA= 25/55/85/105 °C, Run mode, code running from Flash memory, Range 2, HSI16, 1WS	68
Figure 16.	IDD vs VDD, at TA= 25 °C, Low-power run mode, code running from RAM, Range 3, MSI (Range 0) at 64 KHz, 0 WS	72
Figure 17.	IDD vs VDD, at TA= 25/55/ 85/105/125 °C, Stop mode with RTC enabled and running on LSE Low drive	73
Figure 18.	IDD vs VDD, at TA= 25/55/85/105/125 °C, Stop mode with RTC disabled, all clocks off	74
Figure 19.	High-speed external clock source AC timing diagram	80
Figure 20.	Low-speed external clock source AC timing diagram	81
Figure 21.	HSE oscillator circuit diagram.	82
Figure 22.	Typical application with a 32.768 kHz crystal	83
Figure 23.	HSI16 minimum and maximum value versus temperature	84
Figure 24.	VIH/VIL versus VDD (CMOS I/Os)	94
Figure 25.	VIH/VIL versus VDD (TTL I/Os)	94
Figure 26.	I/O AC characteristics definition	97
Figure 27.	Recommended NRST pin protection	98
Figure 28.	ADC accuracy characteristics.	101
Figure 29.	Typical connection diagram using the ADC	102
Figure 30.	Power supply and reference decoupling (V_{REF+} not connected to V_{DDA}).	102
Figure 31.	Power supply and reference decoupling (V_{REF+} connected to V_{DDA}).	103
Figure 32.	12-bit buffered/non-buffered DAC.	106
Figure 33.	SPI timing diagram - slave mode and CPHA = 0	112
Figure 34.	SPI timing diagram - slave mode and CPHA = 1 ⁽¹⁾	113
Figure 35.	SPI timing diagram - master mode ⁽¹⁾	113
Figure 36.	I ² S slave timing diagram (Philips protocol) ⁽¹⁾	115
Figure 37.	I ² S master timing diagram (Philips protocol) ⁽¹⁾	115
Figure 38.	USB timings: definition of data signal rise and fall time	117
Figure 39.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline	119
Figure 40.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint.	121
Figure 41.	LQFP100 marking example (package top view)	121
Figure 42.	UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball	

3 Functional overview

3.1 Low-power modes

The ultra-low-power STM32L083xx support dynamic voltage scaling to optimize its power consumption in Run mode. The voltage from the internal low-drop regulator that supplies the logic can be adjusted according to the system's maximum operating frequency and the external voltage supply.

There are three power consumption ranges:

- Range 1 (V_{DD} range limited to 1.71-3.6 V), with the CPU running at up to 32 MHz
- Range 2 (full V_{DD} range), with a maximum CPU frequency of 16 MHz
- Range 3 (full V_{DD} range), with a maximum CPU frequency limited to 4.2 MHz

Seven low-power modes are provided to achieve the best compromise between low-power consumption, short startup time and available wakeup sources:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs. Sleep mode power consumption at 16 MHz is about 1 mA with all peripherals off.

- **Low-power run mode**

This mode is achieved with the multispeed internal (MSI) RC oscillator set to the low-speed clock (max 131 kHz), execution from SRAM or Flash memory, and internal regulator in low-power mode to minimize the regulator's operating current. In Low-power run mode, the clock frequency and the number of enabled peripherals are both limited.

- **Low-power sleep mode**

This mode is achieved by entering Sleep mode with the internal voltage regulator in low-power mode to minimize the regulator's operating current. In Low-power sleep mode, both the clock frequency and the number of enabled peripherals are limited; a typical example would be to have a timer running at 32 kHz.

When wakeup is triggered by an event or an interrupt, the system reverts to the Run mode with the regulator on.

Stop mode with RTC

The Stop mode achieves the lowest power consumption while retaining the RAM and register contents and real time clock. All clocks in the V_{CORE} domain are stopped, the PLL, MSI RC, HSE crystal and HSI RC oscillators are disabled. The LSE or LSI is still running. The voltage regulator is in the low-power mode.

Some peripherals featuring wakeup capability can enable the HSI RC during Stop mode to detect their wakeup condition.

The device can be woken up from Stop mode by any of the EXTI line, in 3.5 μ s, the processor can serve the interrupt or resume the code. The EXTI line source can be any GPIO. It can be the PVD output, the comparator 1 event or comparator 2 event (if internal reference voltage is on), it can be the RTC alarm/tamper/timestamp/wakeup events, the USB/USART/I2C/LPUART/LPTIMER wakeup events.

3.4.3 Voltage regulator

The regulator has three operation modes: main (MR), low power (LPR) and power down.

- MR is used in Run mode (nominal regulation)
- LPR is used in the Low-power run, Low-power sleep and Stop modes
- Power down is used in Standby mode. The regulator output is high impedance, the kernel circuitry is powered down, inducing zero consumption but the contents of the registers and RAM are lost except for the standby circuitry (wakeup logic, IWDG, RTC, LSI, LSE crystal 32 KHz oscillator, RCC_CSR).

3.5 Clock management

The clock controller distributes the clocks coming from different oscillators to the core and the peripherals. It also manages clock gating for low-power modes and ensures clock robustness. It features:

- **Clock prescaler**
To get the best trade-off between speed and current consumption, the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler.
- **Safe clock switching**
Clock sources can be changed safely on the fly in Run mode through a configuration register.
- **Clock management**
To reduce power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- **System clock source**
Three different clock sources can be used to drive the master clock SYSCLK:
 - 1-25 MHz high-speed external crystal (HSE), that can supply a PLL
 - 16 MHz high-speed internal RC oscillator (HSI), trimmable by software, that can supply a PLLMultispeed internal RC oscillator (MSI), trimmable by software, able to generate 7 frequencies (65 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.1 MHz, 4.2 MHz). When a 32.768 kHz clock source is available in the system (LSE), the MSI frequency can be trimmed by software down to a $\pm 0.5\%$ accuracy.
- **Auxiliary clock source**
Two ultra-low-power clock sources that can be used to drive the LCD controller and the real-time clock:
 - 32.768 kHz low-speed external crystal (LSE)
 - 37 kHz low-speed internal RC (LSI), also used to drive the independent watchdog. The LSI clock can be measured using the high-speed internal RC oscillator for greater precision.
- **RTC and LCD clock source**
The LSI, LSE or HSE sources can be chosen to clock the RTC and the LCD, whatever the system clock.
- **USB clock source**
A 48 MHz clock trimmed through the USB SOF or LSE supplies the USB interface.

3.6 Low-power real-time clock and backup registers

The real time clock (RTC) and the 5 backup registers are supplied in all modes including standby mode. The backup registers are five 32-bit registers used to store 20 bytes of user application data. They are not reset by a system reset, or when the device wakes up from Standby mode.

The RTC is an independent BCD timer/counter. Its main features are the following:

- Calendar with subsecond, seconds, minutes, hours (12 or 24 format), week day, date, month, year, in BCD (binary-coded decimal) format
- Automatically correction for 28, 29 (leap year), 30, and 31 day of the month
- Two programmable alarms with wake up from Stop and Standby mode capability
- Periodic wakeup from Stop and Standby with programmable resolution and period
- On-the-fly correction from 1 to 32767 RTC clock pulses. This can be used to synchronize it with a master clock.
- Reference clock detection: a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision.
- Digital calibration circuit with 1 ppm resolution, to compensate for quartz crystal inaccuracy
- 2 anti-tamper detection pins with programmable filter. The MCU can be woken up from Stop and Standby modes on tamper event detection.
- Timestamp feature which can be used to save the calendar content. This function can be triggered by an event on the timestamp pin, or by a tamper event. The MCU can be woken up from Stop and Standby modes on timestamp event detection.

The RTC clock sources can be:

- A 32.768 kHz external crystal
- A resonator or oscillator
- The internal low-power RC oscillator (typical frequency of 37 kHz)
- The high-speed external clock

3.7 General-purpose inputs/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions, and can be individually remapped using dedicated alternate function registers. All GPIOs are high current capable. Each GPIO output, speed can be slowed (40 MHz, 10 MHz, 2 MHz, 400 kHz). The alternate function configuration of I/Os can be locked if needed following a specific sequence in order to avoid spurious writing to the I/O registers. The I/O controller is connected to a dedicated IO bus with a toggling speed of up to 32 MHz.

Extended interrupt/event controller (EXTI)

The extended interrupt/event controller consists of 29 edge detector lines used to generate interrupt/event requests. Each line can be individually configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 84 GPIOs can be connected to the 16 configurable interrupt/event lines. The 13 other lines are connected to PVD, RTC, USB, USARTs, I2C, LPUART, LPTIMER or comparator events.

3.19.3 Low-power universal asynchronous receiver transmitter (LPUART)

The devices embed one Low-power UART. The LPUART supports asynchronous serial communication with minimum power consumption. It supports half duplex single wire communication and modem operations (CTS/RTS). It allows multiprocessor communication.

The LPUART has a clock domain independent from the CPU clock. It can wake up the system from Stop mode using baudrates up to 46 Kbaud. The Wakeup events from Stop mode are programmable and can be:

- Start bit detection
- Or any received data frame
- Or a specific programmed data frame

Only a 32.768 kHz clock (LSE) is needed to allow LPUART communication up to 9600 baud. Therefore, even in Stop mode, the LPUART can wait for an incoming frame while having an extremely low energy consumption. Higher speed clock can be used to reach higher baudrates.

LPUART interface can be served by the DMA controller.

3.19.4 Serial peripheral interface (SPI)/Inter-integrated sound (I2S)

Up to two SPIs are able to communicate at up to 16 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes.

The USARTs with synchronous capability can also be used as SPI master.

One standard I2S interfaces (multiplexed with SPI2) is available. It can operate in master or slave mode, and can be configured to operate with a 16-/32-bit resolution as input or output channels. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When the I2S interfaces is configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

The SPIs can be served by the DMA controller.

Refer to [Table 14](#) for the differences between SPI1 and SPI2.

Table 14. SPI/I2S implementation

SPI features ⁽¹⁾	SPI1	SPI2
Hardware CRC calculation	X	X
I2S mode	-	X
TI mode	X	X

1. X = supported.



Table 19. Alternate functions port C

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
		SPI1/SPI2/I2S2/ USART1/2/ LPUART1/USB/ LPTIM1/TSC/ TIM2/21/22/ EVENTOUT/ SYS_AF	SPI1/SPI2/I2S2/I2C1/ LCD/ TIM2/21	SPI1/SPI2/I2S2/ LPUART1/ USART5/USB/ LPTIM1/TIM2/3 /EVENTOUT/SYS_AF	I2C1/TSC/ EVENTOUT	I2C1/USART1/2/ LPUART1/ TIM3/22/ EVENTOUT	SPI2/I2S2 /I2C2/ USART1/ TIM2/21/22	I2C1/2/ LPUART1/ USART4/ UASRT5/TIM21/E VENTOUT	I2C3/LPUART1/ COMP1/2/ TIM3
Port C	PC0	LPTIM1_IN1	LCD_SEG18	EVENTOUT	TSC_G7_IO1			LPUART1_RX	I2C3_SCL
	PC1	LPTIM1_OUT	LCD_SEG19	EVENTOUT	TSC_G7_IO2			LPUART1_TX	I2C3_SDA
	PC2	LPTIM1_IN2	LCD_SEG20	SPI2_MISO/ I2S2_MCK	TSC_G7_IO3				
	PC3	LPTIM1_ETR	LCD_SEG21	SPI2_MOSI/ I2S2_SD	TSC_G7_IO4				
	PC4	EVENTOUT	LCD_SEG22	LPUART1_TX					
	PC5		LCD_SEG23	LPUART1_RX	TSC_G3_IO1				
	PC6	TIM22_CH1	LCD_SEG24	TIM3_CH1	TSC_G8_IO1				
	PC7	TIM22_CH2	LCD_SEG25	TIM3_CH2	TSC_G8_IO2				
	PC8	TIM22_ETR	LCD_SEG26	TIM3_CH3	TSC_G8_IO3				
	PC9	TIM21_ETR	LCD_SEG27	USB_OE/TIM3_CH4	TSC_G8_IO4				I2C3_SDA
	PC10	LPUART1_TX	LCD_COM4/LCD_SEG 28/LCD_SEG48					USART4_TX	
	PC11	LPUART1_RX	LCD_COM5/LCD_SEG 29/LCD_SEG49					USART4_RX	
	PC12		LCD_COM6/LCD_SEG 30/LCD_SEG50	USART5_TX				USART4_CK	
	PC13								
	PC14								
	PC15								



Table 21. Alternate functions port E

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
		SPI1/SPI2/I2S2/ USART1/2/ LPUART1/USB/ LPTIM1/TSC/ TIM2/21/22/ EVENTOUT/ SYS_AF	SPI1/SPI2/I2S2/I2C1 /LCD/TIM2/21	SPI1/SPI2/I2S2/ LPUART1/ USART5/USB/ LPTIM1/TIM2/3 /EVENTOUT/ SYS_AF	I2C1/TSC/ EVENTOUT	I2C1/USART1/2/ LPUART1/ TIM3/22/ EVENTOUT	SPI2/I2S2 /I2C2/ USART1/ TIM2/21/22	I2C1/2/ LPUART1/ USART4/ USART5/TIM21/ EVENTOUT	I2C3/LPUART1/ COMP1/2/TIM3
Port E	PE0	-	LCD_SEG36	EVENTOUT	-	-	-	-	-
	PE1	-	LCD_SEG37	EVENTOUT	-	-	-	-	-
	PE2	-	LCD_SEG38	TIM3_ETR	-	-	-	-	-
	PE3	TIM22_CH1	LCD_SEG39	TIM3_CH1	-	-	-	-	-
	PE4	TIM22_CH2	-	TIM3_CH2	-	-	-	-	-
	PE5	TIM21_CH1	-	TIM3_CH3	-	-	-	-	-
	PE6	TIM21_CH2	-	TIM3_CH4	-	-	-	-	-
	PE7	-	LCD_SEG45	-	-	-	-	USART5_CK/U SART5_RTS_D E	-
	PE8	-	LCD_SEG46	-	-	-	-	USART4_TX	-
	PE9	TIM2_CH1	LCD_SEG47	TIM2_ETR	-	-	-	USART4_RX	-
	PE10	TIM2_CH2	LCD_SEG40	-	-	-	-	USART5_TX	-
	PE11	TIM2_CH3	-	-	-	-	-	USART5_RX	-
	PE12	TIM2_CH4	-	SPI1_NSS	-	-	-	-	-
	PE13	-	LCD_SEG41	SPI1_SCK	-	-	-	-	-
	PE14	-	LCD_SEG42	SPI1_MISO	-	-	-	-	-
	PE15	-	LCD_SEG43	SPI1_MOSI	-	-	-	-	-

6.1.6 Power supply scheme

Figure 11. Power supply scheme

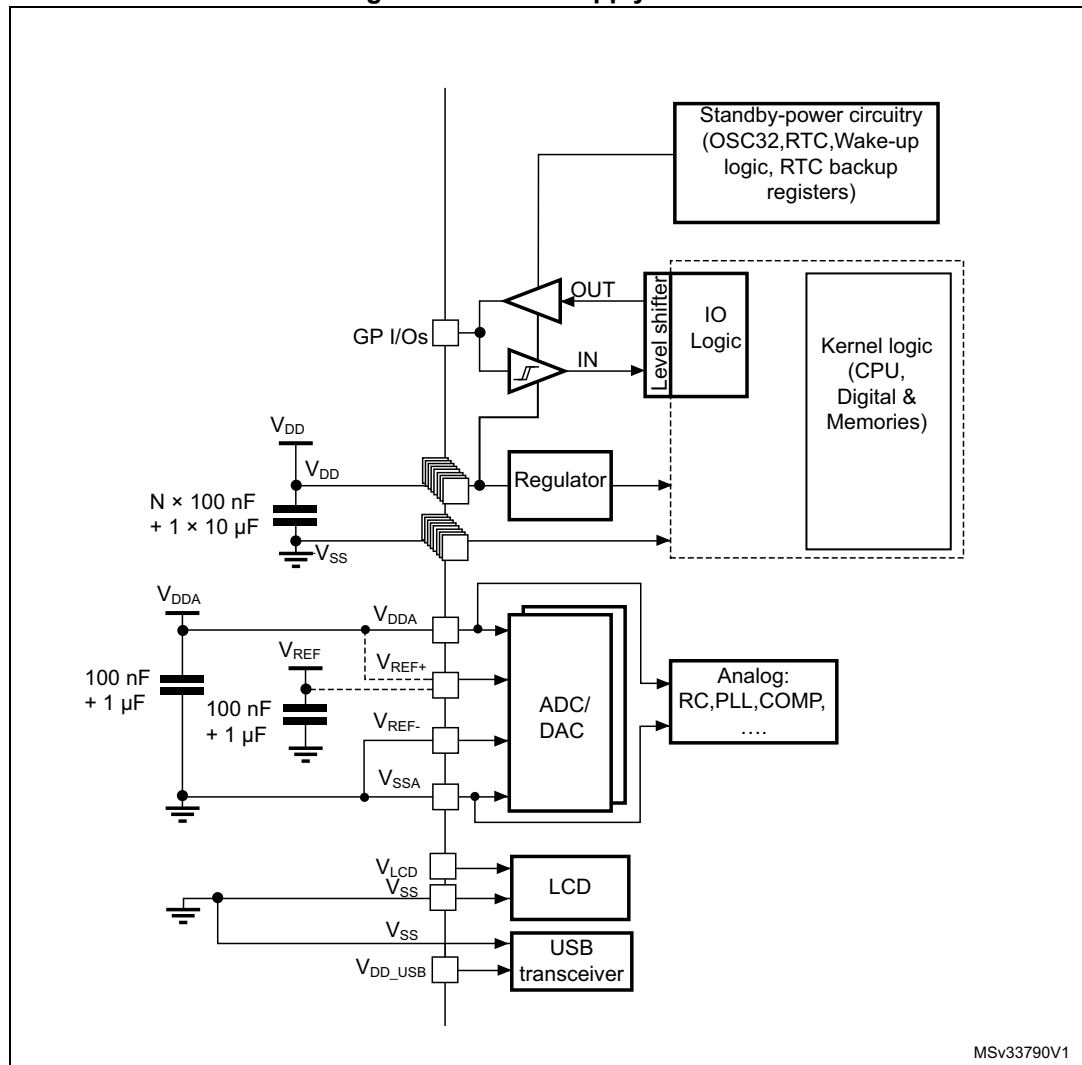
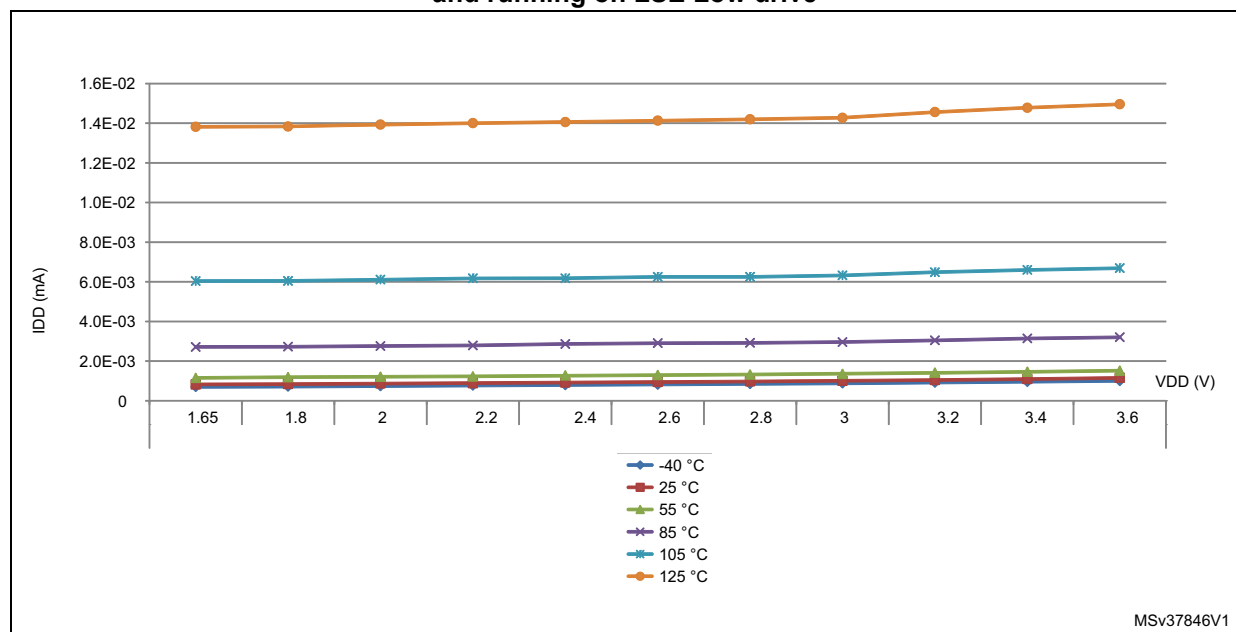


Table 37. Typical and maximum current consumptions in Stop mode

Symbol	Parameter	Conditions	Typ	Max ⁽¹⁾	Unit
I_{DD} (Stop)	Supply current in Stop mode	$T_A = -40$ to 25°C	0,43	1,00	μA
		$T_A = 55^\circ\text{C}$	0,735	2,50	
		$T_A = 85^\circ\text{C}$	2,25	4,90	
		$T_A = 105^\circ\text{C}$	5,3	13,00	
		$T_A = 125^\circ\text{C}$	12,5	28,00	

1. Guaranteed by characterization results at 125°C , unless otherwise specified.

Figure 17. I_{DD} vs V_{DD} , at $T_A = 25/55/ 85/105/125^\circ\text{C}$, Stop mode with RTC enabled and running on LSE Low drive

Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 46](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

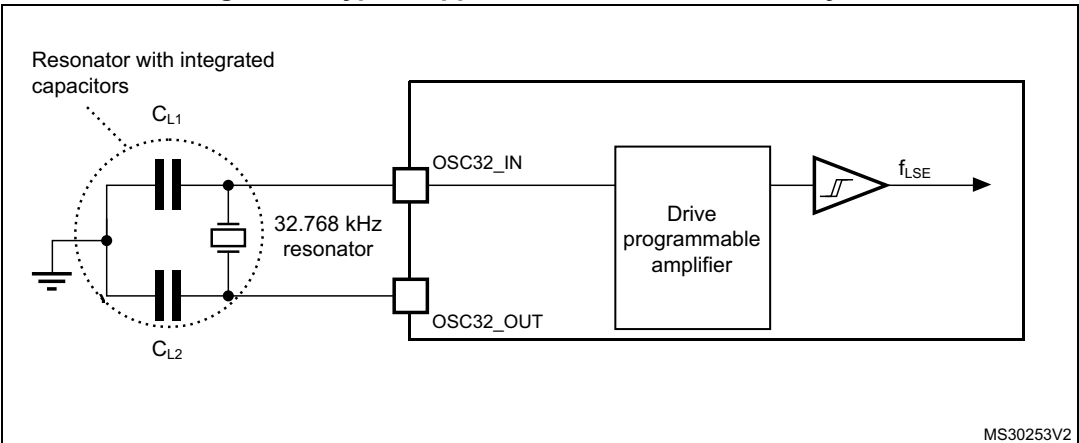
Table 46. LSE oscillator characteristics⁽¹⁾

Symbol	Parameter	Conditions ⁽²⁾	Min ⁽²⁾	Typ	Max	Unit
f_{LSE}	LSE oscillator frequency		-	32.768	-	kHz
G_m	Maximum critical crystal transconductance	LSEDRV[1:0]=00 lower driving capability	-	-	0.5	$\mu A/V$
		LSEDRV[1:0]= 01 medium low driving capability	-	-	0.75	
		LSEDRV[1:0] = 10 medium high driving capability	-	-	1.7	
		LSEDRV[1:0]=11 higher driving capability	-	-	2.7	
$t_{SU(LSE)}$ ⁽³⁾	Startup time	V_{DD} is stabilized	-	2	-	s

1. Guaranteed by design.
2. Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".
3. Guaranteed by characterization results. $t_{SU(LSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer. To increase speed, address a lower-drive quartz with a high- driver mode.

Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website www.st.com.

Figure 22. Typical application with a 32.768 kHz crystal



Note: An external resistor is not required between OSC32_IN and OSC32_OUT and it is forbidden to add one.

Table 50. MSI oscillator characteristics (continued)

Symbol	Parameter	Condition	Typ	Max	Unit
$t_{\text{STAB(MSI)}}^{(2)}$	MSI oscillator stabilization time	MSI range 0	-	40	μs
		MSI range 1	-	20	
		MSI range 2	-	10	
		MSI range 3	-	4	
		MSI range 4	-	2.5	
		MSI range 5	-	2	
		MSI range 6, Voltage range 1 and 2	-	2	
		MSI range 3, Voltage range 3	-	3	
$f_{\text{OVER(MSI)}}$	MSI oscillator frequency overshoot	Any range to range 5	-	4	MHz
		Any range to range 6	-	6	

1. This is a deviation for an individual part, once the initial frequency has been measured.
2. Guaranteed by characterization results.

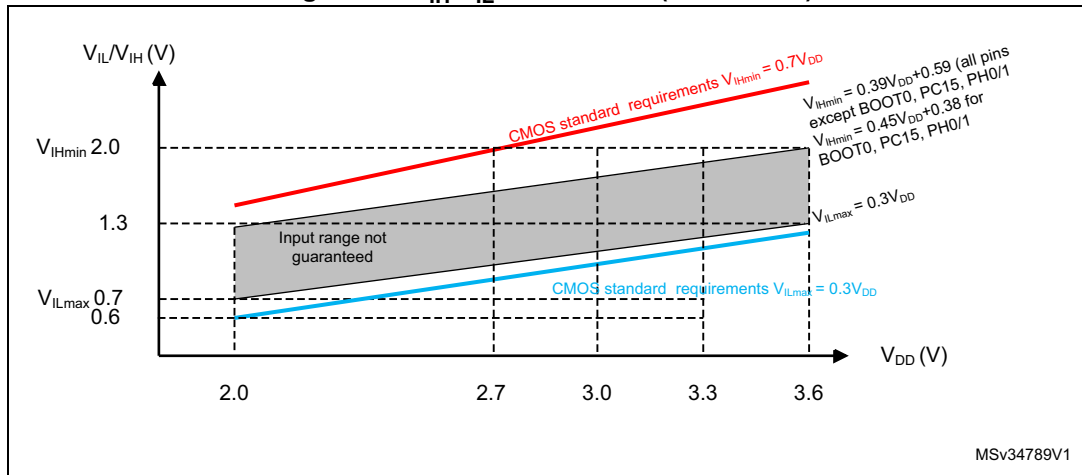
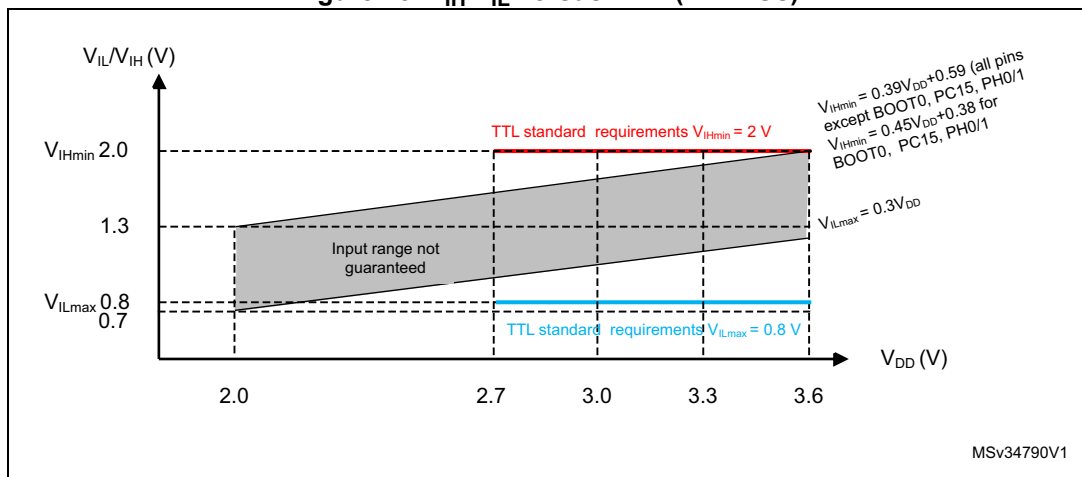
6.3.8 PLL characteristics

The parameters given in [Table 51](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 26](#).

Table 51. PLL characteristics

Symbol	Parameter	Value			Unit
		Min	Typ	Max ⁽¹⁾	
$f_{\text{PLL_IN}}$	PLL input clock ⁽²⁾	2	-	24	MHz
	PLL input clock duty cycle	45	-	55	%
$f_{\text{PLL_OUT}}$	PLL output clock	2	-	32	MHz
t_{LOCK}	PLL input = 16 MHz PLL VCO = 96 MHz	-	115	160	μs
Jitter	Cycle-to-cycle jitter	-		± 600	ps
$I_{\text{DDA(PLL)}}$	Current consumption on V_{DDA}	-	220	450	μA
$I_{\text{DD(PLL)}}$	Current consumption on V_{DD}	-	120	150	

1. Guaranteed by characterization results.
2. Take care of using the appropriate multiplier factors so as to have PLL input clock values compatible with the range defined by $f_{\text{PLL_OUT}}$.

Figure 24. V_{IH}/V_{IL} versus V_{DD} (CMOS I/Os)Figure 25. V_{IH}/V_{IL} versus V_{DD} (TTL I/Os)

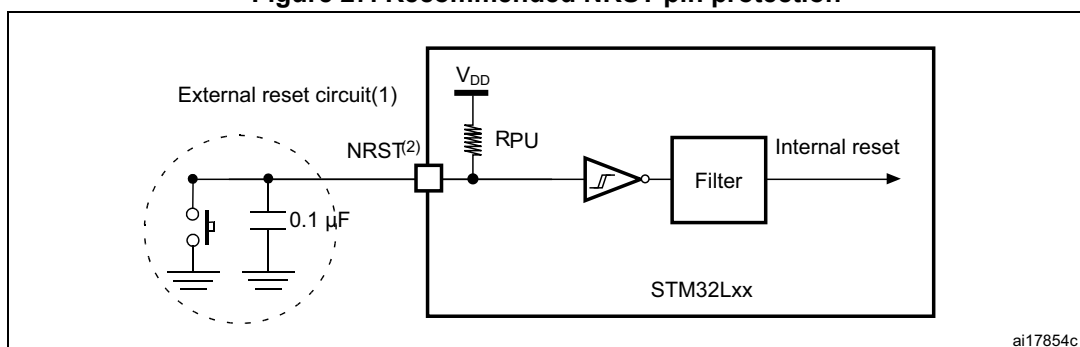
Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to ± 8 mA, and sink or source up to ± 15 mA with the non-standard V_{OL}/V_{OH} specifications given in [Table 61](#).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in [Section 6.2](#):

- The sum of the currents sourced by all the I/Os on V_{DD} , plus the maximum Run consumption of the MCU sourced on V_{DD} , cannot exceed the absolute maximum rating $I_{VDD(\Sigma)}$ (see [Table 24](#)).
- The sum of the currents sunk by all the I/Os on V_{SS} plus the maximum Run consumption of the MCU sunk on V_{SS} cannot exceed the absolute maximum rating $I_{VSS(\Sigma)}$ (see [Table 24](#)).

Figure 27. Recommended NRST pin protection



1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the $V_{IL(NRST)}$ max level specified in [Table 63](#). Otherwise the reset will not be taken into account by the device.

6.3.15 12-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 64](#) are derived from tests performed under ambient temperature, f_{PCLK} frequency and V_{DDA} supply voltage conditions summarized in [Table 26: General operating conditions](#).

Note: It is recommended to perform a calibration after each power-up.

Table 64. ADC characteristics

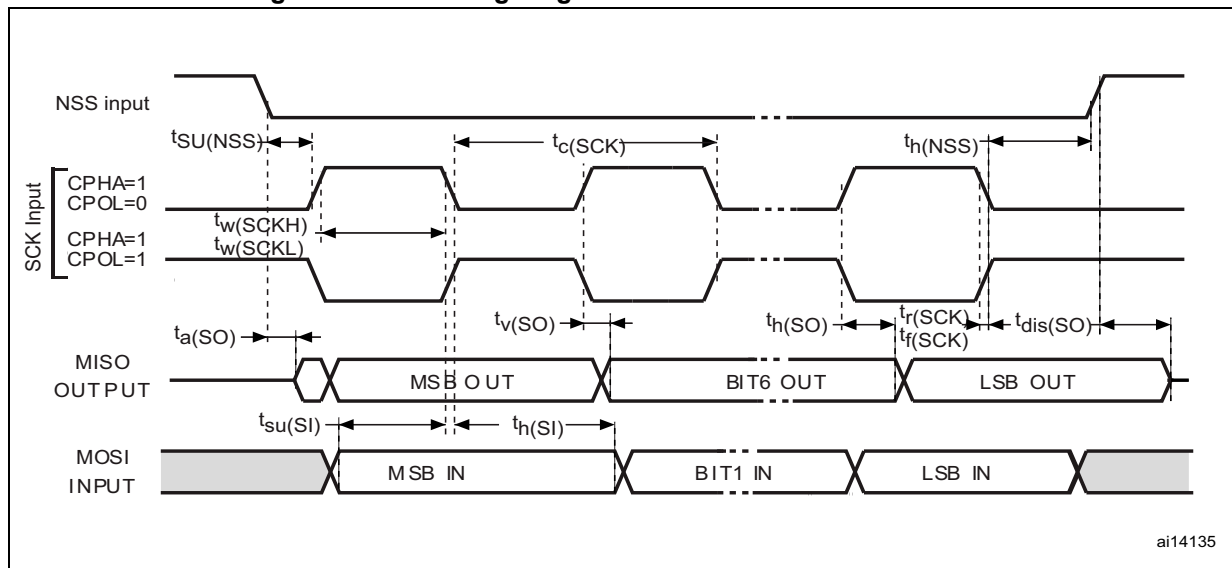
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DDA}	Analog supply voltage for ADC on	Fast channel	1.65	-	3.6	V
		Standard channel	1.75 ⁽¹⁾	-	3.6	
V_{REF+}	Positive reference voltage	-	1.65		V_{DDA}	V
V_{REF-}	Negative reference voltage	-	-	0	-	
$I_{DDA(ADC)}$	Current consumption of the ADC on V_{DDA} and V_{REF+}	1.14 Msps	-	200	-	μA
		10 ksps	-	40	-	
	Current consumption of the ADC on V_{DD} ⁽²⁾	1.14 Msps	-	70	-	
		10 ksps	-	1	-	
f_{ADC}	ADC clock frequency	Voltage scaling Range 1	0.14	-	16	MHz
		Voltage scaling Range 2	0.14	-	8	
		Voltage scaling Range 3	0.14	-	4	
$f_S^{(3)}$	Sampling rate	12-bit resolution	0.01	-	1.14	MHz
$f_{TRIG}^{(3)}$	External trigger frequency	$f_{ADC} = 16$ MHz, 12-bit resolution	-	-	941	kHz
		-	-	-	17	1/ f_{ADC}
V_{AIN}	Conversion voltage range	-	0	-	V_{REF+}	V
$R_{AIN}^{(3)}$	External input impedance	See Equation 1 and Table 65 for details	-	-	50	kΩ
$R_{ADC}^{(3)(4)}$	Sampling switch resistance	-	-	-	1	kΩ

Table 76. SPI characteristics in voltage Range 2 ⁽¹⁾

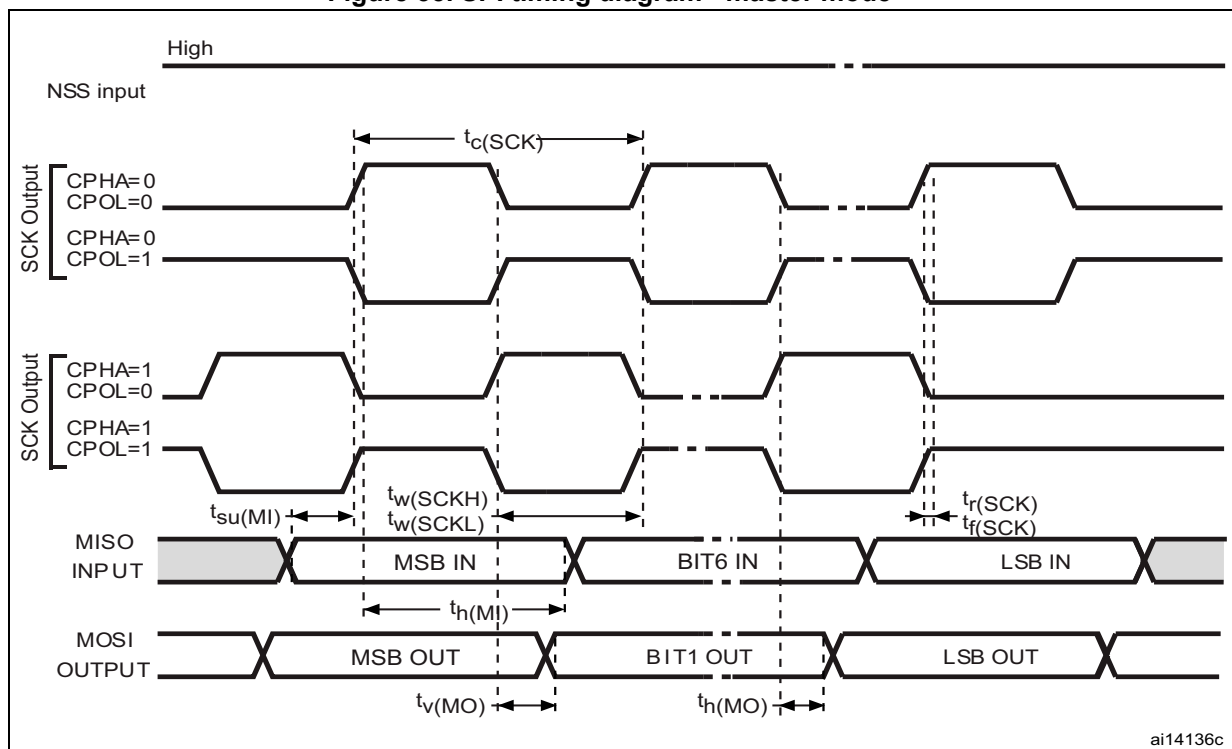
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{SCK} $1/t_{c(SCK)}$	SPI clock frequency	Master mode	-	-	8	MHz
		Slave mode Transmitter $1.65 < V_{DD} < 3.6V$			8	
		Slave mode Transmitter $2.7 < V_{DD} < 3.6V$			8 ⁽²⁾	
$Duty_{(SCK)}$	Duty cycle of SPI clock frequency	Slave mode	30	50	70	%
$t_{su(NSS)}$	NSS setup time	Slave mode, SPI presc = 2	$4 \cdot T_{pclk}$	-	-	ns
$t_{h(NSS)}$	NSS hold time	Slave mode, SPI presc = 2	$2 \cdot T_{pclk}$	-	-	
$t_{w(SCKH)}$ $t_{w(SCKL)}$	SCK high and low time	Master mode	$T_{pclk} - 2$	T_{pclk}	$T_{pclk} + 2$	
$t_{su(MI)}$	Data input setup time	Master mode	0	-	-	
$t_{su(SI)}$		Slave mode	3	-	-	
$t_{h(MI)}$	Data input hold time	Master mode	11	-	-	
$t_{h(SI)}$		Slave mode	4.5	-	-	
$t_{a(SO)}$	Data output access time	Slave mode	18	-	52	
$t_{dis(SO)}$	Data output disable time	Slave mode	12	-	42	
$t_{v(SO)}$	Data output valid time	Slave mode	-	20	56.5	
$t_{v(MO)}$		Master mode	-	5	9	
$t_{h(SO)}$	Data output hold time	Slave mode	13	-	-	
$t_{h(MO)}$		Master mode	3	-	-	

1. Guaranteed by characterization results.

2. The maximum SPI clock frequency in slave transmitter mode is determined by the sum of $t_{v(SO)}$ and $t_{su(MI)}$ which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having $t_{su(MI)} = 0$ while $Duty_{(SCK)} = 50\%$.

Figure 34. SPI timing diagram - slave mode and CPHA = 1⁽¹⁾

1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

Figure 35. SPI timing diagram - master mode⁽¹⁾

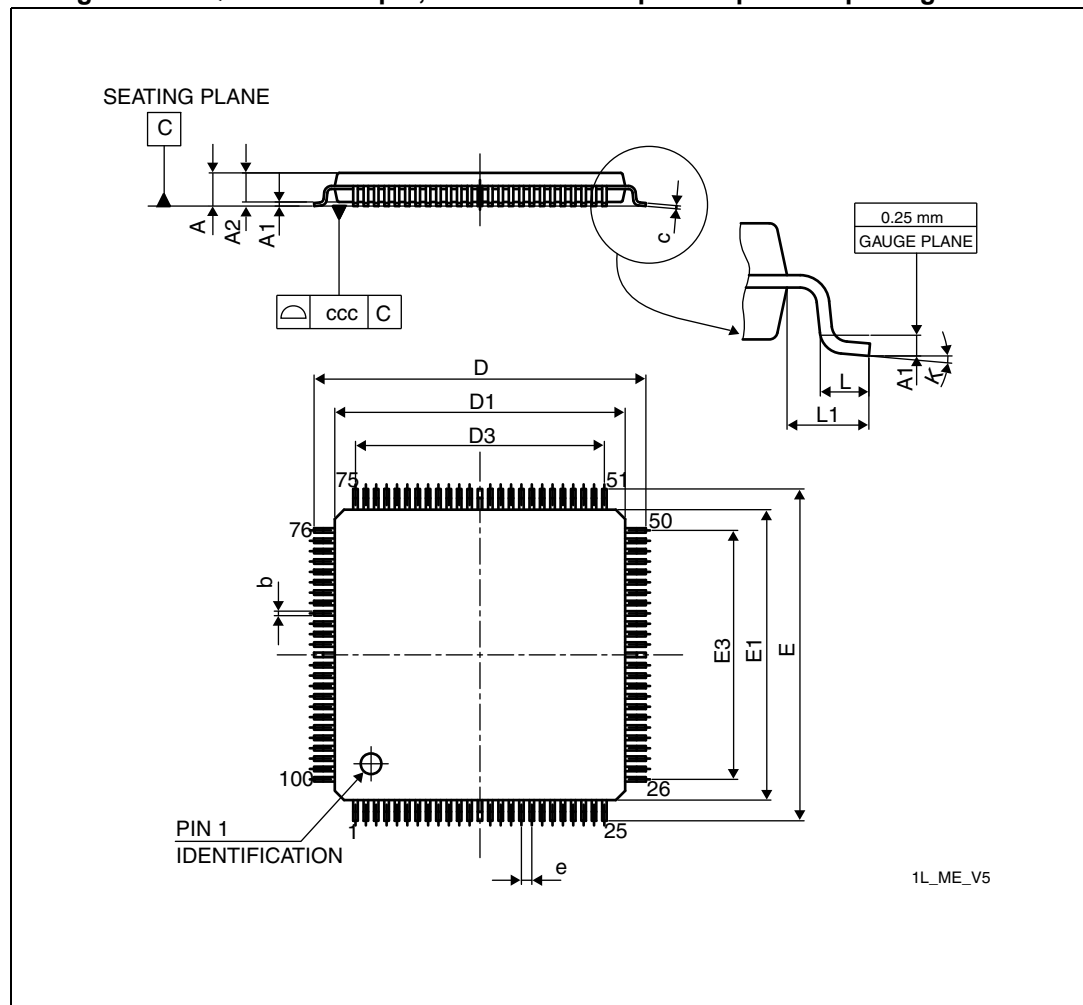
1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status *are available at* www.st.com. ECOPACK[®] is an ST trademark.

7.1 LQFP100 package information

Figure 39. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline



1. Drawing is not to scale. Dimensions are in millimeters.

7.6 Thermal characteristics

The maximum chip-junction temperature, $T_J \text{ max}$, in degrees Celsius, may be calculated using the following equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

Where:

- $T_A \text{ max}$ is the maximum ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W,
- $P_D \text{ max}$ is the sum of $P_{INT} \text{ max}$ and $P_{I/O} \text{ max}$ ($P_D \text{ max} = P_{INT} \text{ max} + P_{I/O} \text{ max}$),
- $P_{INT} \text{ max}$ is the product of I_{DD} and V_{DD} , expressed in Watts. This is the maximum chip internal power.

$P_{I/O} \text{ max}$ represents the maximum power dissipation on output pins where:

$$P_{I/O} \text{ max} = \Sigma (V_{OL} \times I_{OL}) + \Sigma ((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 90. Thermal characteristics

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP48 - 7 x 7 mm / 0.5 mm pitch	54	°C/W
	Thermal resistance junction-ambient LQFP64 - 10 x 10 mm / 0.5 mm pitch	46	
	Thermal resistance junction-ambient TFBGA64 - 5 x 5 mm / 0.5 mm pitch	64	
	Thermal resistance junction-ambient LQFP100 - 14 x 14 mm / 0.5 mm pitch	41	
	Thermal resistance junction-ambient UFBGA100 - 7 x 7 mm / 0.5 mm pitch	57	

9 Revision history

Table 92. Document revision history

Date	Revision	Changes
03-Aug-2015	1	Initial release
26-Oct-2015	2	<p>Added UFBGA100 package.</p> <p>Changed confidentiality level to public.</p> <p>Updated datasheet status to “production data”.</p> <p>Modified ultra-low-power platform features on cover page.</p> <p>Changed LCD_VLCD1 into LCD_VLCD2 in Section 3.13.2: VLCD voltage monitoring.</p> <p>In Section 6: Electrical characteristics, updated notes related to values guaranteed by characterization.</p> <p>Updated ΔV_{SS} definition to include V_{REF-} in Table 23: Voltage characteristics.</p> <p>Added ΣV_{DD_USB} and updated $\Sigma I_{IO(PIN)}$ in Figure 24: Current characteristics.</p> <p>Updated Table 56: EMI characteristics.</p> <p>Updated f_{TRIG} and V_{AIN} maximum value, added V_{REF+} and V_{REF-} in Table 64: ADC characteristics.</p> <p>Updated Figure 53: LQFP48 marking example (package top view).</p>